

Product Summary

| $V_{(BR)DSS}$ | $R_{DS(on)MAX}$ | I_D |
|---------------|-----------------|-------|
| 60V | 44mΩ@10V | 5A |
| | 49mΩ@4.5V | |

Feature

- Trench Power MV MOSFET technology
- High density cell design for Low $R_{DS(ON)}$
- Suffix“-Q1”for AEC-Q101

Application

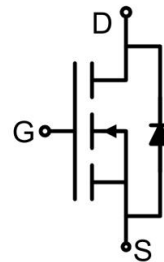
- PWM application
- Load switch

Package

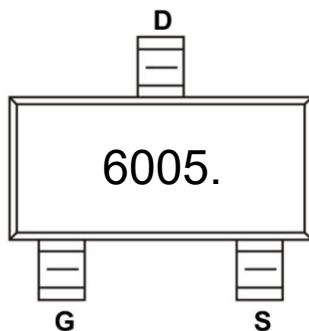


SOT-23-3L

Circuit diagram



Marking



Absolute maximum ratings ($T_A=25^\circ\text{C}$ unless otherwise noted)

| Parameter | Symbol | Value | Unit |
|---|-----------------|------------|---------------------------|
| Drain-Source Voltage | V_{DS} | 60 | V |
| Gate-Source Voltage | V_{GS} | ± 20 | V |
| Continuous Drain Current | I_D | 5 | A |
| Pulsed Drain Current ²⁾ | I_{DM} | 25 | A |
| Power Dissipation | P_D | 2.5 | W |
| Thermal Resistance from Junction to Ambient ³⁾ | $R_{\theta JA}$ | 50 | $^\circ\text{C}/\text{W}$ |
| Junction Temperature | T_J | 150 | $^\circ\text{C}$ |
| Storage Temperature | T_{STG} | -55 ~ +150 | $^\circ\text{C}$ |

Electrical characteristics ($T_J=25^\circ\text{C}$ unless otherwise noted)

| Parameter | Symbol | Test Condition | Min. | Typ. | Max. | Unit |
|---|---------------|--|------|------|-----------|---------------|
| Static Characteristics | | | | | | |
| Drain-source breakdown voltage | $V_{(BR)DSS}$ | $V_{GS} = 0V, I_D = 250\mu\text{A}$ | 60 | | | V |
| Zero gate voltage drain current | I_{DSS} | $V_{DS} = 60V, V_{GS} = 0V$ | | | 1 | μA |
| Gate-body leakage current | I_{GSS} | $V_{GS} = \pm 20V, V_{DS} = 0V$ | | | ± 100 | nA |
| Gate threshold voltage | $V_{GS(th)}$ | $V_{DS} = V_{GS}, I_D = 250\mu\text{A}$ | 1.0 | 1.5 | 2.5 | V |
| Drain-source on-resistance | $R_{DS(on)}$ | $V_{GS} = 10V, I_D = 5.0A$ | | 35 | 44 | m Ω |
| | | $V_{GS} = 4.5V, I_D = 4.0A$ | | 39 | 49 | |
| Dynamic characteristics¹⁾ | | | | | | |
| Input Capacitance | C_{iss} | $V_{DS} = 30V, V_{GS} = 0V, f = 1\text{MHz}$ | | 1018 | | pF |
| Output Capacitance | C_{oss} | | | 70 | | |
| Reverse Transfer Capacitance | C_{rss} | | | 62 | | |
| Total Gate Charge | Q_g | $V_{GS} = 10V, V_{DS} = 30V, I_D = 10A$ | | 26.4 | | nC |
| Gate-Source Charge | Q_{gs} | | | 5.4 | | |
| Gate-Drain Charge | Q_{gd} | | | 6.5 | | |
| Turn-on delay time | $t_{d(on)}$ | $V_{DD} = 30V, V_{GS} = 10V, I_D = 2A, R_{GEN} = 3\Omega, R_L = 1\Omega$ | | 10 | | nS |
| Turn-on rise time | t_r | | | 20 | | |
| Turn-off delay time | $t_{d(off)}$ | | | 29 | | |
| Turn-off fall time | t_f | | | 21 | | |
| Source-Drain Diode characteristics | | | | | | |
| Diode Forward Current | I_S | | | | 5 | A |
| Diode Forward voltage | V_{SD} | $V_{GS} = 0V, I_S = 5A$ | | | 1.2 | V |
| Reverse Recovery Time | t_{rr} | $I_F = 20A, di/dt = 500A/\mu\text{s}$ | | 23 | | ns |
| Reverse Recovery Charge | Q_{rr} | | | 11.7 | | nC |

Notes:

- 1) Guaranteed by design, not subject to production.
- 2) Pulse Test: Pulse Width $\leq 300\mu\text{s}$, Duty cycle $\leq 2\%$.
- 3) $R_{\theta JA}$ is the sum of the junction-to-lead and lead-to-ambient thermal resistance, where the lead thermal reference is defined as the solder mounting surface of the drain pins. $R_{\theta JL}$ is guaranteed by design, while $R_{\theta JA}$ is determined by the board design. The maximum rating presented here is based on mounting on a 1 in 2 pad of 2oz copper.

Typical Characteristics

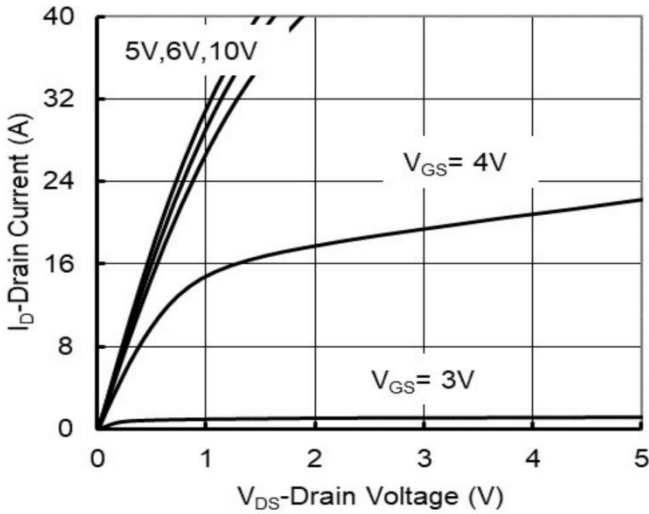


Figure 1. Output Characteristics

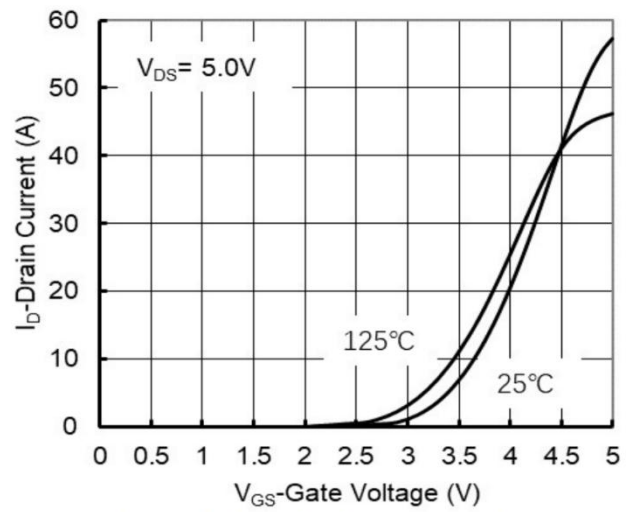


Figure 2. Transfer Characteristics

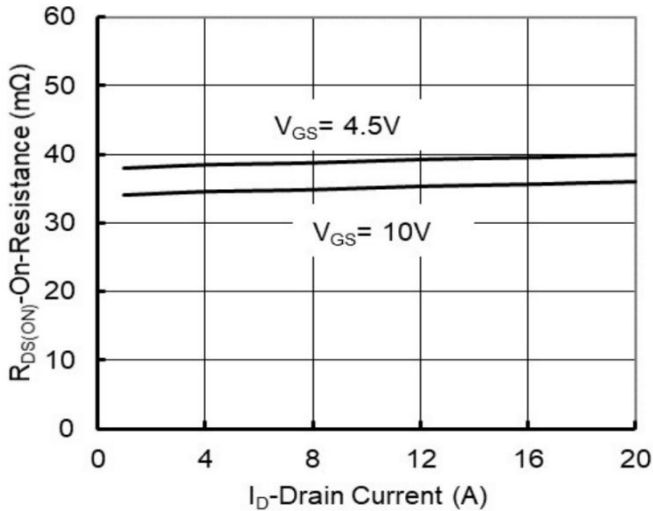


Figure 3. On-Resistance vs. Drain Current and Gate Voltage

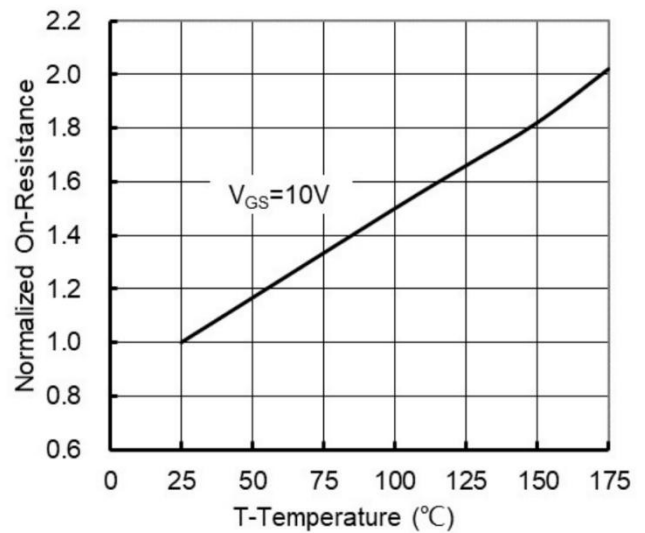


Figure 4. On-Resistance vs. Junction Temperature

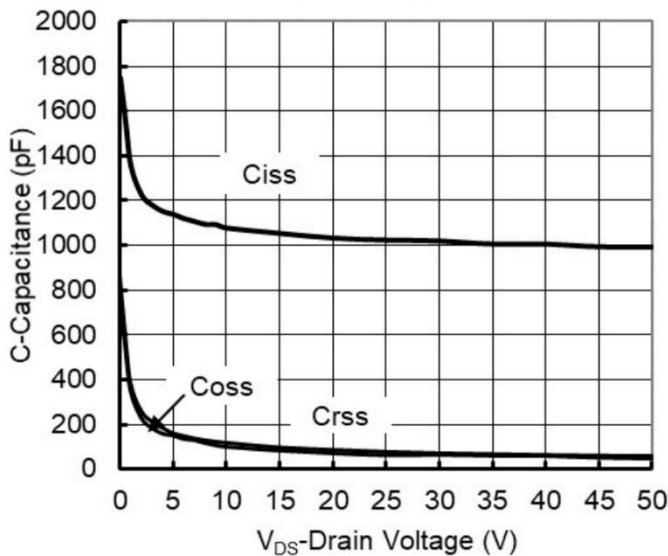


Figure 5. Capacitance Characteristics

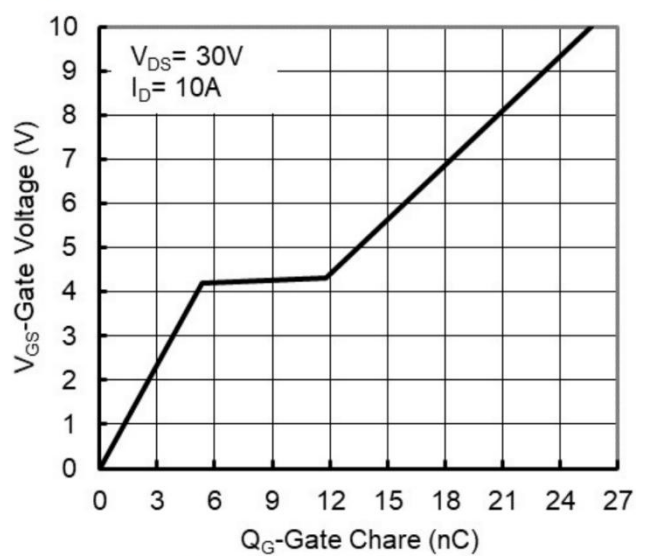


Figure 6. Gate Charge

Typical Characteristics

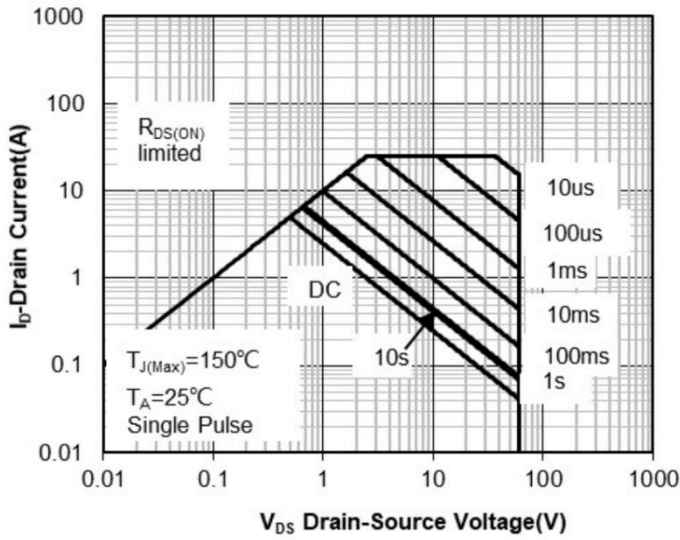


Figure 7. Safe Operation Area

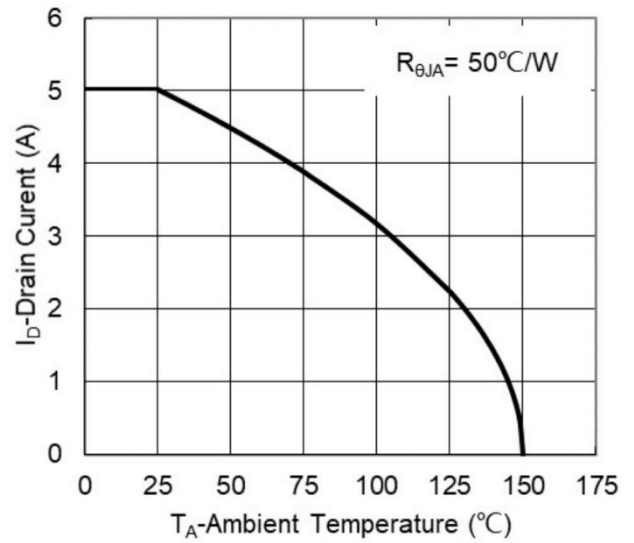


Figure 8. Maximum Continuous Drain Current vs Ambient Temperature

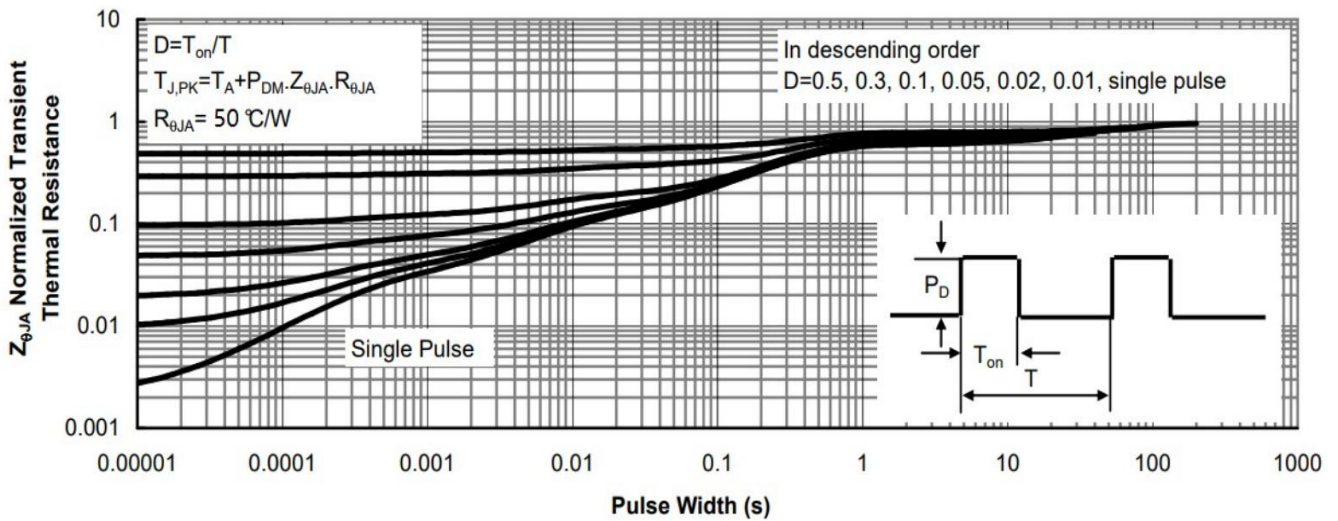
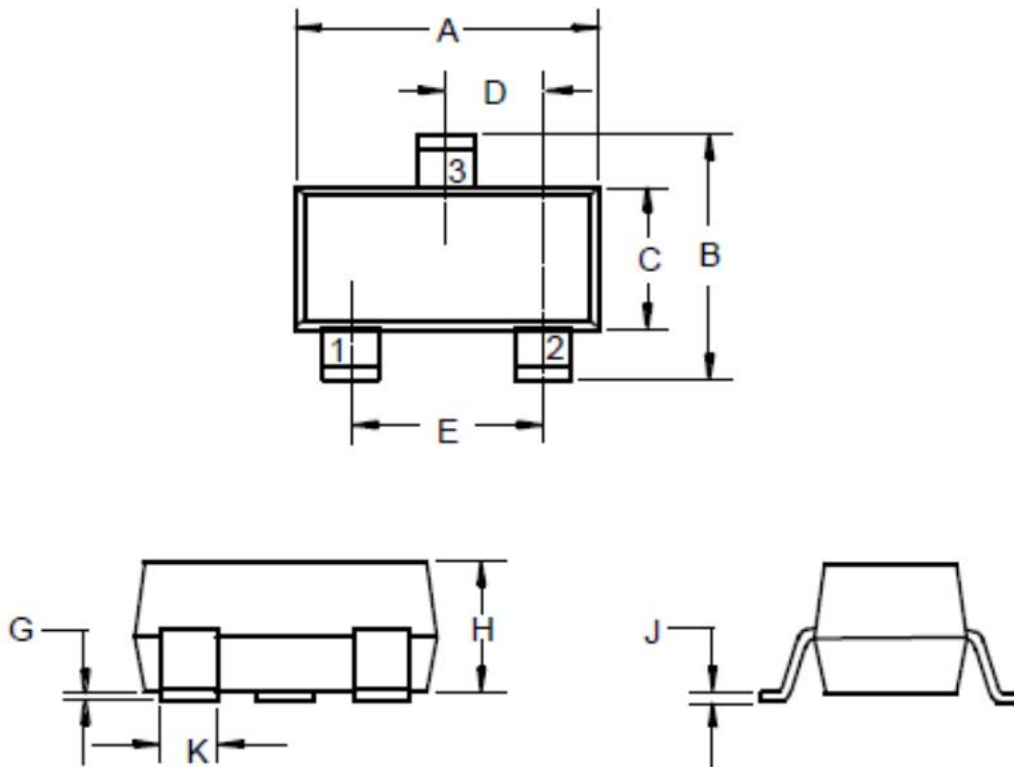


Figure 9. Normalized Maximum Transient Thermal Impedance

SOT-23-3L Package Information



| Symbol | Dimensions In Millimeters | | Dimensions In Inches | |
|--------|---------------------------|-------|----------------------|-------|
| | Min. | Max. | Min. | Max. |
| A | 2.820 | 3.020 | 0.111 | 0.119 |
| B | 2.650 | 2.950 | 0.104 | 0.116 |
| C | 1.500 | 1.700 | 0.059 | 0.067 |
| D | 0.865 | 1.015 | 0.034 | 0.040 |
| E | 1.800 | 2.000 | 0.071 | 0.079 |
| G | 0.000 | 0.200 | 0.000 | 0.008 |
| H | 1.050 | 1.250 | 0.041 | 0.049 |
| J | 0.100 | 0.200 | 0.004 | 0.008 |
| K | 0.300 | 0.500 | 0.012 | 0.020 |